

## Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDC)
- Built-In Biasing Resistors
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The DDA (XXXX) UQ are suitable for automotive applications requiring specific change control; these parts are AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**

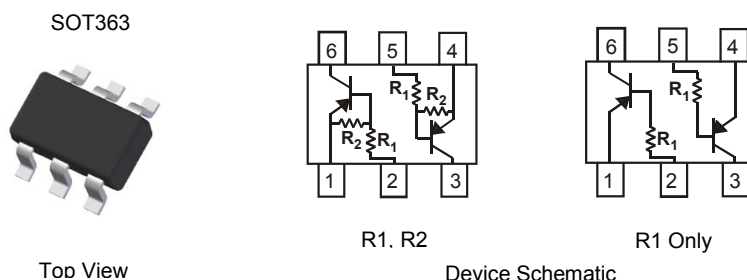
<https://www.diodes.com/quality/product-definitions/>

Part Number	R1 (NOM)	R2 (NOM)
DDA124EU	22kΩ	22kΩ
DDA144EU	47kΩ	47kΩ
DDA114YU	10kΩ	47kΩ
DDA123JU	2.2kΩ	47kΩ
DDA114EU	10kΩ	10kΩ

## Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 Ⓜ3
- Weight: 0.006 grams (Approximate)

Part Number	R1 Only
DDA113TU	1kΩ
DDA143TU	4.7kΩ
DDA114TU	10kΩ

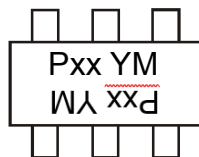


## Ordering Information (Notes 4, 5)

Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DDA124EU-7-F	Active	Standard	P17	7	8	3,000
DDA124EUQ-7-F	Active	Automotive	P17	7	8	3,000
DDA124EUQ-13-F	Active	Automotive	P17	13	8	10,000
DDA144EU-7-F	Active	Standard	P20	7	8	3,000
DDA144EUQ-7-F	Active	Automotive	P20	7	8	3,000
DDA114YU-7-F	Active	Standard	P14	7	8	3,000
DDA114YUQ-7-F	NRND (Use ADA114YUQ)	Automotive	P14	7	8	3,000
DDA123JU-7-F	Active	Standard	P06	7	8	3,000
DDA114EU-7-F	Active	Standard	P13	7	8	3,000
DDA114EUQ-7-F	NRND (Use ADA114EUQ)	Automotive	P13	7	8	3,000
DDA113TU-7-F	Active	Standard	P01	7	8	3,000
DDA143TU-7-F	Active	Standard	P07	7	8	3,000
DDA143TUQ-7-F	Active	Automotive	P07	7	8	3,000
DDA143TUQ-13-F	Active	Automotive	P07	13	8	10,000
DDA114TU-7-F	Active	Standard	P12	7	8	3,000
DDA114TUQ-7-F	Active	Automotive	P12	7	8	3,000
DDA114TUQ-13-F	Active	Automotive	P12	13	8	10,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.
  5. NRND = Not Recommended for New Design.

## Marking Information



Pxx = Product Type Marking Code (See Ordering Information)  
 YM = Date Code Marking  
 Y = Year (ex: 1 = 2021)  
 M = Month (ex: 9 = September)

### Date Code Key

Year	2018	.....	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	F	.....	I	J	K	L	M	N	O	P	R	S
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

## Absolute Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Supply Voltage (1) to (6) and (4) to (3)	V <sub>CC</sub>	-50	V
Input Voltage (1) to (2) and (4) to (5)	V <sub>IN</sub>	+10 to -40 +10 to -40 +6 to -40 +5 to -12 +10 to -40 +5V Max +5V Max +5V Max	V
Output Current	I <sub>O</sub>	-30 -30 -70 -100 -50 -100 -100 -100	mA
Output Current	I <sub>C(max)</sub>	-100	mA

## Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Notes 6, 7)	P <sub>D</sub>	200	mW
Thermal Resistance, Junction to Ambient Air (Note 6)	R <sub>θJA</sub>	625	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes: 6. Mounted on FR-4 PC Board with minimum recommended pad layout.  
 7. 150mW per element must not be exceeded.

**Electrical Characteristics** (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic (DDA113TU & DDA143TU & DDA114TU only)	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CB0</sub>	-50	—	—	V	I <sub>C</sub> = -50μA
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	-50	—	—	V	I <sub>C</sub> = -1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5	—	—	V	I <sub>E</sub> = -50μA
Collector Cutoff Current	I <sub>CB0</sub>	—	—	-0.5	μA	V <sub>CB</sub> = -50V
Emitter Cutoff Current	I <sub>EBO</sub>	—	—	-0.5	μA	V <sub>EB</sub> = -4V
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	—	—	-0.3	V	I <sub>C</sub> /I <sub>B</sub> = -2.5mA / -0.25mA DDA143TU I <sub>C</sub> /I <sub>B</sub> = -1mA / -0.1mA DDA114TU I <sub>C</sub> /I <sub>B</sub> = -10mA / -1mA DDA113TU
DC Current Transfer Ratio	h <sub>FE</sub>	100 160	250 —	600 600	—	I <sub>C</sub> = -1mA, V <sub>CE</sub> = -5V I <sub>C</sub> = -1mA, V <sub>CE</sub> = -5V DDA143TU/Q
Input Resistor (R <sub>1</sub> ) Tolerance	ΔR <sub>1</sub>	-30	—	+30	%	—
Gain-Bandwidth Product (Note 8)	f <sub>T</sub>	—	250	—	MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = 5mA, f = 100MHz

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition	
Input Voltage	V <sub>I(off)</sub>	DDA124EU	-0.5	-1.1	—	V	V <sub>CC</sub> = -5V, I <sub>O</sub> = -100μA
		DDA144EU	-0.5	-1.1			
Input Voltage	V <sub>I(on)</sub>	DDA114YU	-0.3	—	—	V	V <sub>O</sub> = -0.3, I <sub>O</sub> = -5mA
		DDA123JU	-0.5	—			
Input Voltage	V <sub>I(on)</sub>	DDA114EU	-0.5	-1.1	—	V	V <sub>O</sub> = -0.3, I <sub>O</sub> = -2mA
		DDA124EU	—	—			
Input Voltage	V <sub>I(on)</sub>	DDA144EU	—	-1.9	—	V	V <sub>O</sub> = -0.3, I <sub>O</sub> = -1mA
		DDA114YU	—	-1.9			
Input Voltage	V <sub>I(on)</sub>	DDA123JU	—	-1.1	—	V	V <sub>O</sub> = -0.3, I <sub>O</sub> = -5mA
		DDA114EU	—	-1.9			
Output Voltage	V <sub>O(on)</sub>	DDA124EU	—	-0.1	—	V	I <sub>O</sub> /I <sub>I</sub> = -10mA / -0.5mA
		DDA144EU	—	-0.1			
Output Voltage	V <sub>O(on)</sub>	DDA114YU	—	-0.1	—	V	I <sub>O</sub> /I <sub>I</sub> = -10mA / -0.5mA
		DDA123JU	—	-0.1			
Output Voltage	V <sub>O(on)</sub>	DDA114EU	—	-0.1	—	V	I <sub>O</sub> /I <sub>I</sub> = -5mA / -0.25mA
		DDA124EU	—	-0.1			
Output Voltage	V <sub>O(on)</sub>	DDA144EU	—	-0.1	—	V	I <sub>O</sub> /I <sub>I</sub> = -5mA / -0.25mA
		DDA114YU	—	-0.1			
Input Current	I <sub>I</sub>	DDA123JU	—	—	—	mA	V <sub>I</sub> = -5V
		DDA114EU	—	—			
Input Current	I <sub>I</sub>	DDA124EU	—	—	—	mA	V <sub>I</sub> = -5V
		DDA144EU	—	—			
Input Current	I <sub>I</sub>	DDA114YU	—	—	—	mA	V <sub>I</sub> = -5V
		DDA123JU	—	—			
Input Current	I <sub>I</sub>	DDA123JU	—	—	—	mA	V <sub>I</sub> = -5V
		DDA114EU	—	—			
Output Current	I <sub>O(off)</sub>	—	—	-0.5	μA	V <sub>CC</sub> = -50V, V <sub>I</sub> = -0V	
DC Current Gain	G <sub>I</sub>	DDA124EU	56	—	—	—	V <sub>O</sub> = -5V, I <sub>O</sub> = -5mA
		DDA124EUQ	60	—			
DC Current Gain	G <sub>I</sub>	DDA144EU	68	—	—	—	V <sub>O</sub> = -5V, I <sub>O</sub> = -5mA
		DDA114YU	68	—			
DC Current Gain	G <sub>I</sub>	DDA123JU	80	—	—	—	V <sub>O</sub> = -5V, I <sub>O</sub> = -10mA
		DDA114EU	30	—			
DC Current Gain	G <sub>I</sub>	30	—	—	—	V <sub>O</sub> = -5V, I <sub>O</sub> = -5mA	
Input Resistor (R <sub>1</sub> ) Tolerance	ΔR <sub>1</sub>	-30	—	+30	%	—	
Resistance Ratio Tolerance	R <sub>2</sub> /R <sub>1</sub>	-20	—	+20	%	—	
Gain-Bandwidth Product (Note 8)	f <sub>T</sub>	—	250	—	MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = -5mA, f = 100MHz	

Note: 8. Transistor - For Reference Only.

**Typical Curves – DDA123JU** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

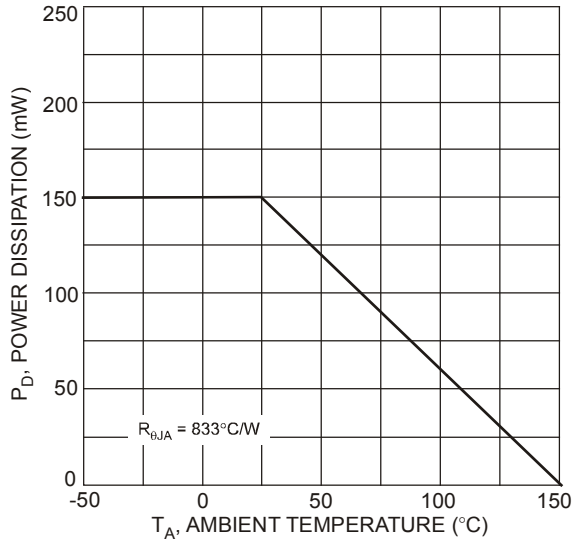


Fig. 1 Power Dissipation vs. Ambient Temperature

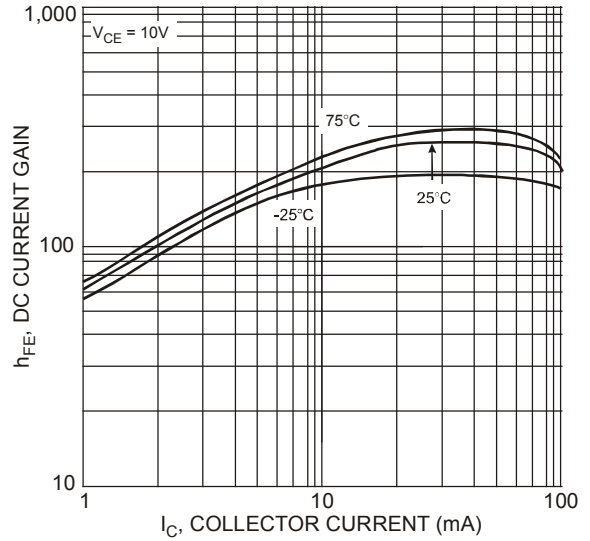


Fig. 2 Typical DC Current Gain vs. Collector Current

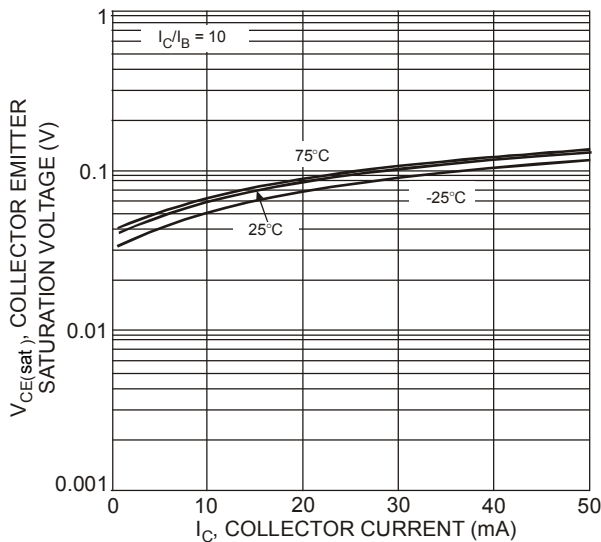


Fig. 3 Typical Collector Emitter Saturation Voltage vs. Collector Current

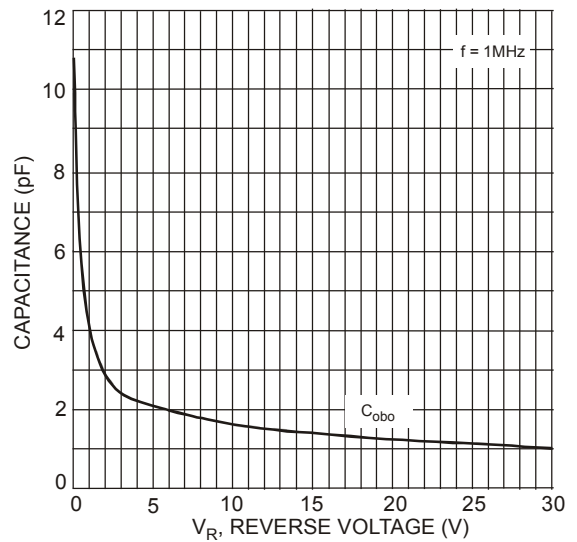


Fig. 4 Typical Capacitance Characteristics

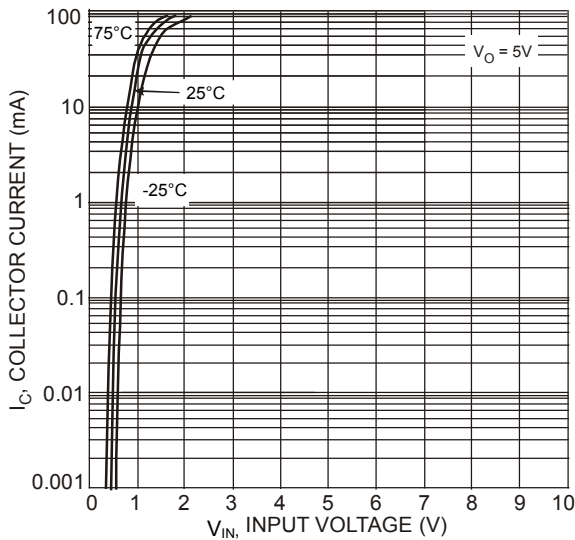


Fig. 5 Collector Current vs. Input Voltage

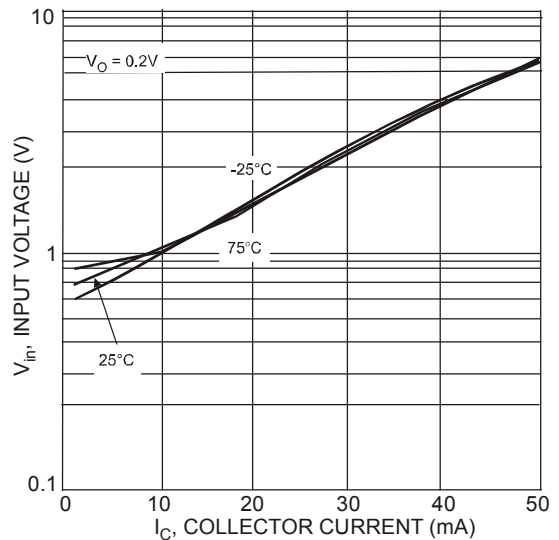


Fig. 6 Input Voltage vs. Collector Current

**Typical Curves – DDA114TU** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

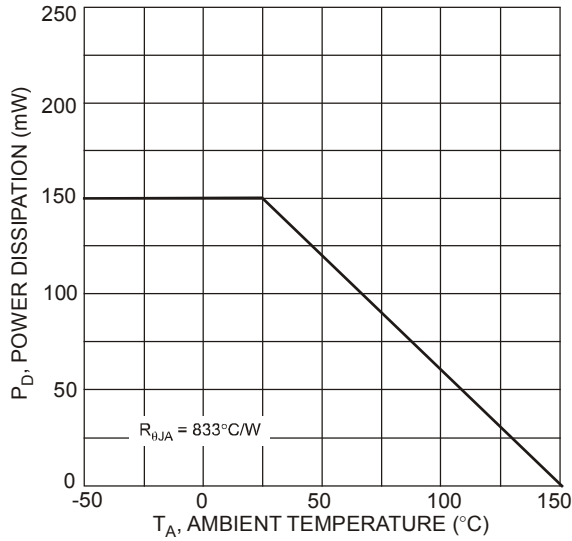


Fig.7 Power Dissipation vs. Ambient Temperature

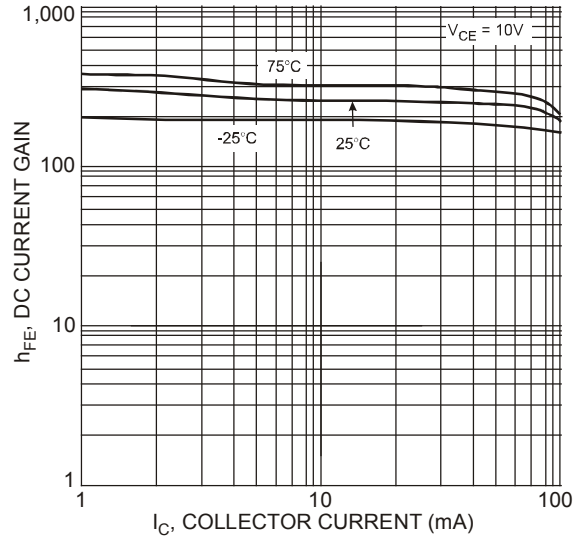


Fig.8 Typical DC Current Gain vs. Collector Current

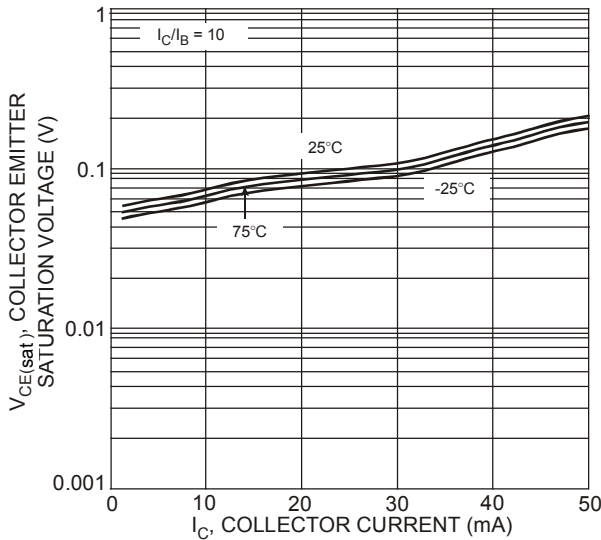


Fig.9 Typical Collector Emitter Saturation Voltage vs. Collector Current

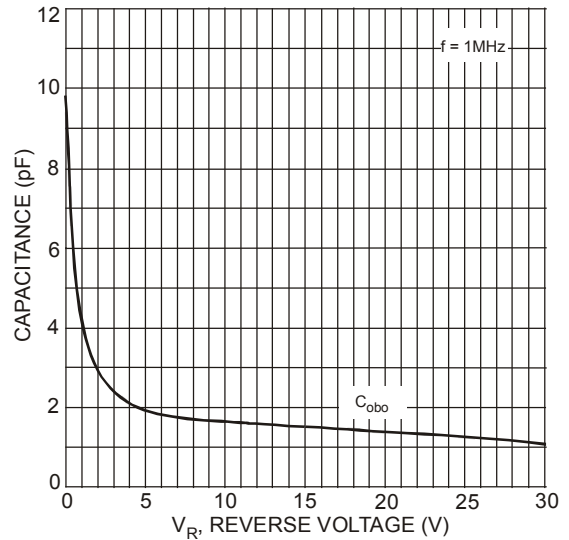


Fig.10 Typical Capacitance Characteristics

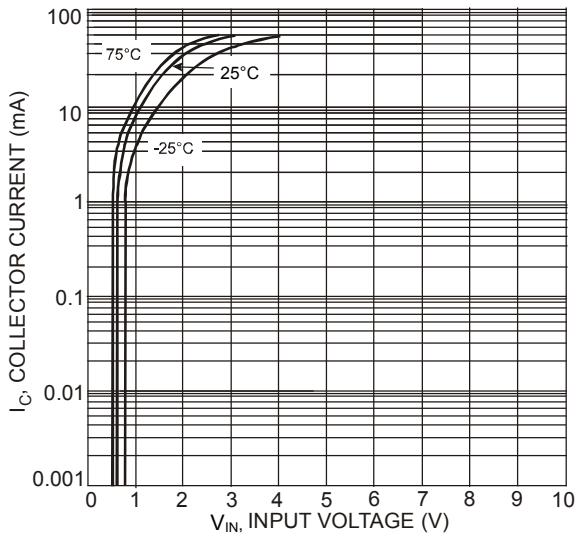


Fig.11 Collector Current vs. Input Voltage

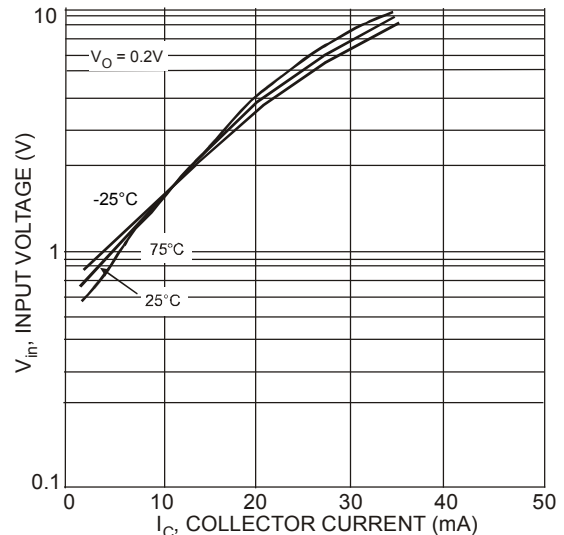
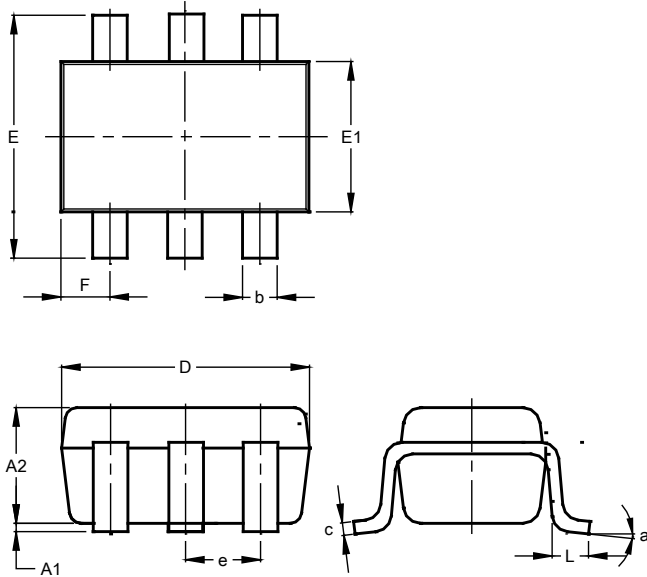


Fig.12 Input Voltage vs. Collector Current

**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT363**

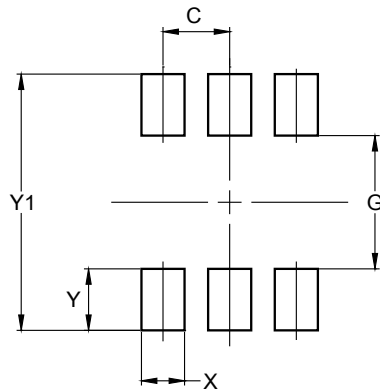


SOT363			
Dim	Min	Max	Typ
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.10	0.30	0.25
c	0.10	0.22	0.11
D	1.80	2.20	2.15
E	2.00	2.20	2.10
E1	1.15	1.35	1.30
e	0.650 BSC		
F	0.40	0.45	0.425
L	0.25	0.40	0.30
a	0°	8°	--
<b>All Dimensions in mm</b>			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT363**



Dimensions	Value (in mm)
C	0.650
G	1.300
X	0.420
Y	0.600
Y1	2.500

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